## NCE P-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE2301F uses advanced trench technology to provide excellent  $R_{\rm DS(ON)}$ , low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

#### **General Features**

•  $V_{DS} = -20V, I_{D} = -2 A$ 

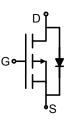
 $R_{DS(ON)}$  < 150m $\Omega$  @  $V_{GS}$ =-2.5V

 $R_{DS(ON)} < 120 m\Omega$  @  $V_{GS}$ =-4.5V

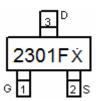
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### **Application**

- PWM applications
- Load switch



Schematic diagram



Marking and pin assignment



SOT-23 top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301F X	NCE2301F	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Drain Current-Continuous	I <sub>D</sub>	-2.0	Α
Drain Current -Pulsed (Note 1)	I <sub>DM</sub>	-10	Α
Maximum Power Dissipation	P <sub>D</sub>	0.7	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	178	°C/W
	00/1	-	

## **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-20		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	-1	μA



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# NCE2301F

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
Drain Course On Ctata Desistance	Б	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2 A	-	88	120	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.8A	-	120	150	mΩ
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =-5 $V$ , $I_{D}$ =-2 $A$	4	-	-	S
Dynamic Characteristics (Note4)			•			·
Input Capacitance	C <sub>lss</sub>	\/ 40\/\/ 0\/	-	285	-	PF
Output Capacitance	Coss	$V_{DS}$ =-10V, $V_{GS}$ =0V,	-	58	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	32	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	9.8	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-10V, $R_L$ =5 $\Omega$	-	4.9	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-4.5 $V$ , $R_{GEN}$ =3 $\Omega$	-	20.5	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =-10V,I <sub>D</sub> =-2A,	-	2.9	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.45	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-4.5V	-	0.75	-	nC
Drain-Source Diode Characteristics			•	1		1
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}$ =0 $V$ , $I_{S}$ =-2 $A$	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-2.0	Α

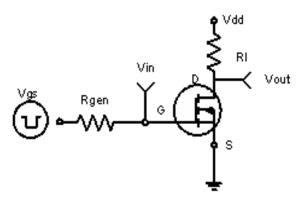
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

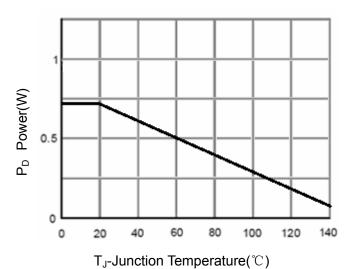
**Pb Free Product** 

## **NCE2301F**

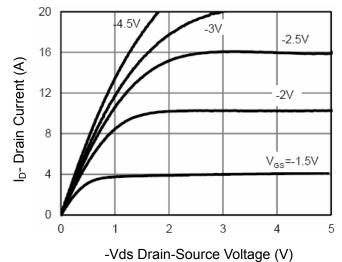
## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

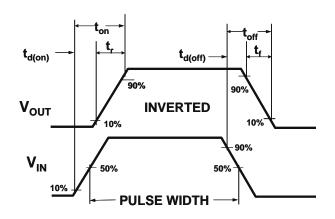
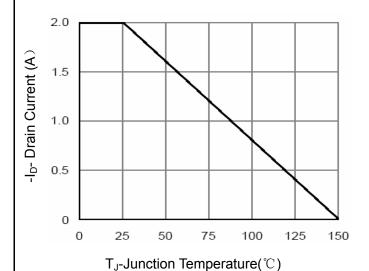


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

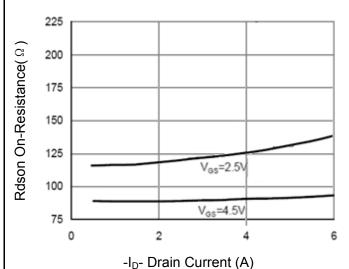
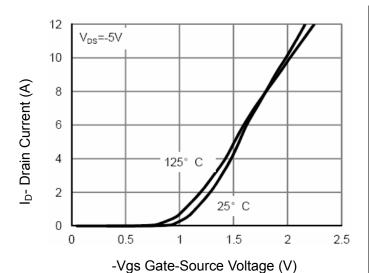


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 

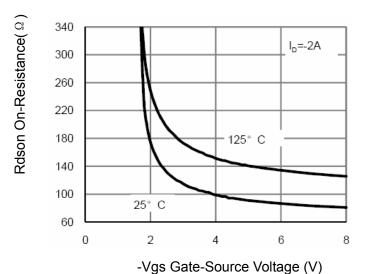


Figure 9 Rdson vs Vgs

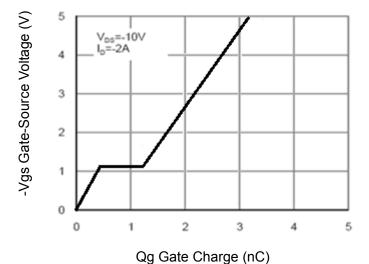
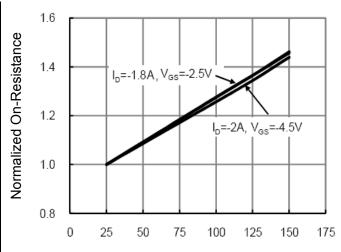


Figure 11 Gate Charge



 $T_J$ -Junction Temperature( ${}^{\circ}$ C) Figure 8 Drain-Source On-Resistance

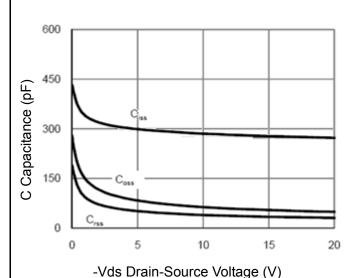


Figure 10 Capacitance vs Vds

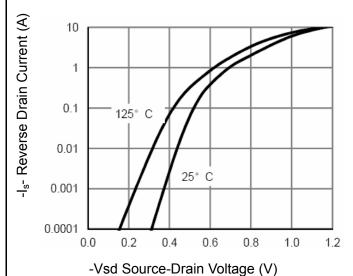
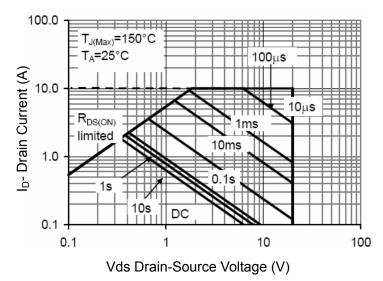


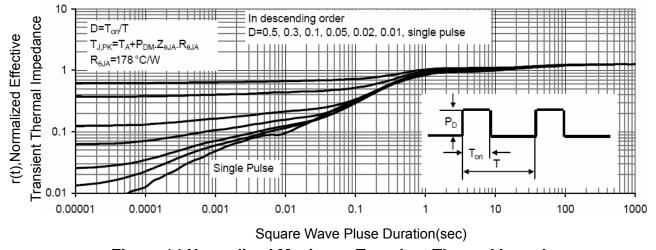
Figure 12 Source- Drain Diode Forward

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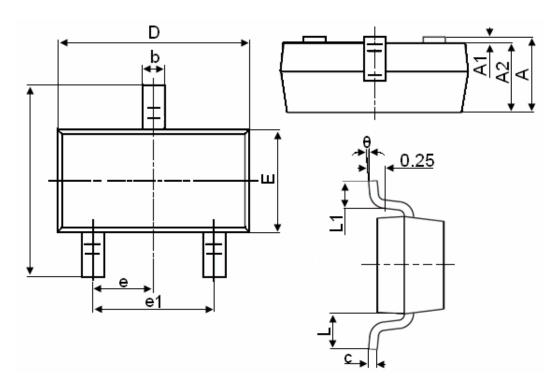
**Figure 13 Safe Operation Area** 



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



## **SOT-23 Package Information**



Symbol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

#### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



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